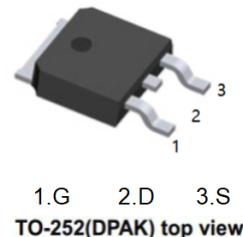


## Features

- V<sub>DS</sub> (V) = 30V
- R<sub>DS(ON)</sub> < 5.8 mΩ (V<sub>GS</sub> = 10V)
- R<sub>DS(ON)</sub> < 8 mΩ (V<sub>GS</sub> = 4.5V)

## Applications

- High Frequency Synchronous Buck  
Converters for Computer Processor Power
- High Frequency Isolated DC-DC  
Converters with Synchronous Rectification  
for Telecom and Industrial Use



## Benefits

- Very Low R<sub>DS(on)</sub> at 4.5V V<sub>GS</sub>
- Ultra-Low Gate Impedance
- Fully Characterized Avalanche Voltage and Current

## Absolute Maximum Ratings

	Parameter	Max.	Units
V <sub>DS</sub>	Drain-to-Source Voltage	30	V
V <sub>GS</sub>	Gate-to-Source Voltage	± 20	
I <sub>D</sub> @ T <sub>C</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	86④	A
I <sub>D</sub> @ T <sub>C</sub> = 100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V	61④	
I <sub>DM</sub>	Pulsed Drain Current ①	340	W
P <sub>D</sub> @ T <sub>C</sub> = 25°C	Maximum Power Dissipation ⑥	75	
P <sub>D</sub> @ T <sub>C</sub> = 100°C	Maximum Power Dissipation ⑥	38	W/°C
	Linear Derating Factor	0.5	
T <sub>J</sub>	Operating Junction and	-55 to + 175	°C
T <sub>STG</sub>	Storage Temperature Range		
	Soldering Temperature, for 10 seconds	300 (1.6mm from case)	

## Thermal Resistance

	Parameter	Typ.	Max.	Units
R <sub>θJC</sub>	Junction-to-Case ⑥	°C/W	2.0	°C/W
R <sub>θJA</sub>	Junction-to-Ambient (PCB Mount) ⑤		50	
R <sub>θJA</sub>	Junction-to-Ambient		110	

## Notes

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Starting T<sub>J</sub> = 25°C, L = 0.605mH, R<sub>G</sub> = 25Ω, I<sub>AS</sub> = 20A.
- ③ Pulse width ≤ 400μs; duty cycle ≤ 2%.
- ④ Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 50A.
- ⑤ When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.
- ⑥ R<sub>θ</sub> is measured at T<sub>J</sub> approximately at 90°C

**Static @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)**

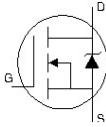
	Parameter	Min.	Typ.	Max.	Units	Conditions
$\text{BV}_{\text{DSS}}$	Drain-to-Source Breakdown Voltage	30			V	$V_{\text{GS}} = 0\text{V}, I_D = 250\mu\text{A}$
$\Delta V_{\text{DSS}/\Delta T_J}$	Breakdown Voltage Temp. Coefficient		20		mV/°C	Reference to $25^\circ\text{C}$ , $I_D = 1\text{mA}$
$R_{\text{DS(on)}}$	Static Drain-to-Source On-Resistance		4.0	5.8	mΩ	$V_{\text{GS}} = 10\text{V}, I_D = 25\text{A}$ ③
			5.8	8.0		$V_{\text{GS}} = 4.5\text{V}, I_D = 20\text{A}$ ③
$V_{\text{GS(th)}}$	Gate Threshold Voltage	1.35	1.80	2.35	V	$V_{\text{DS}} = V_{\text{GS}}, I_D = 50\mu\text{A}$
$\Delta V_{\text{GS(th)}/\Delta T_J}$	Gate Threshold Voltage Coefficient		-8.6		mV/°C	
$I_{\text{DSS}}$	Drain-to-Source Leakage Current			1.0	μA	$V_{\text{DS}} = 24\text{V}, V_{\text{GS}} = 0\text{V}$
				150		$V_{\text{DS}} = 24\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 125^\circ\text{C}$
$I_{\text{GSS}}$	Gate-to-Source Forward Leakage			100	nA	$V_{\text{GS}} = 20\text{V}$
	Gate-to-Source Reverse Leakage			-100		$V_{\text{GS}} = -20\text{V}$
$g_{\text{fs}}$	Forward Transconductance	73			S	$V_{\text{DS}} = 15\text{V}, I_D = 20\text{A}$
$Q_g$	Total Gate Charge		15	23	nC	$V_{\text{DS}} = 15\text{V}$ $V_{\text{GS}} = 4.5\text{V}$ $I_D = 20\text{A}$ See Fig. 15
$Q_{\text{gs}1}$	Pre-Vth Gate-to-Source Charge		3.7			
$Q_{\text{gs}2}$	Post-Vth Gate-to-Source Charge		1.9			
$Q_{\text{gd}}$	Gate-to-Drain Charge		5.7			
$Q_{\text{godr}}$	Gate Charge Overdrive		3.7			
$Q_{\text{sw}}$	Switch Charge ( $Q_{\text{gs}2} + Q_{\text{gd}}$ )		7.6		pF	$V_{\text{GS}} = 0\text{V}$ $V_{\text{DS}} = 15\text{V}$ $f = 1.0\text{MHz}$
$Q_{\text{oss}}$	Output Charge		10			
$R_G$	Gate Resistance		2.0	3.5		
$t_{\text{d(on)}}$	Turn-On Delay Time		12		ns	$V_{\text{DD}} = 15\text{V}, V_{\text{GS}} = 4.5\text{V}$ ③ $I_D = 20\text{A}$ $R_G = 1.8\Omega$ See Fig. 13
$t_r$	Rise Time		49			
$t_{\text{d(off)}}$	Turn-Off Delay Time		15			
$t_f$	Fall Time		16			
$C_{\text{iss}}$	Input Capacitance		2150		pF	$V_{\text{GS}} = 0\text{V}$ $V_{\text{DS}} = 15\text{V}$ $f = 1.0\text{MHz}$
$C_{\text{oss}}$	Output Capacitance		480			
$C_{\text{rss}}$	Reverse Transfer Capacitance		205			

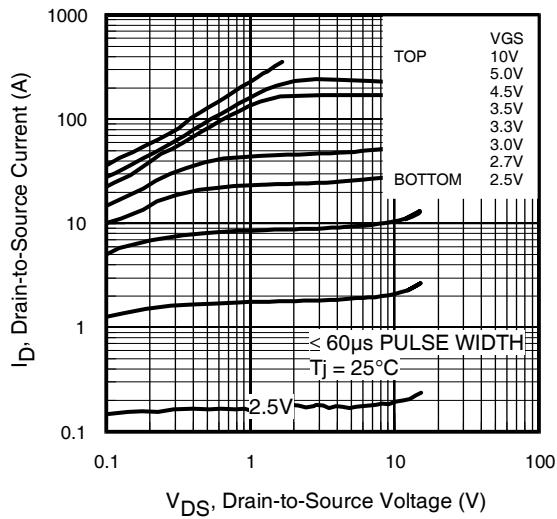
**Avalanche Characteristics**

	Parameter	Typ.	Max.	Units
$E_{\text{AS}}$	Single Pulse Avalanche Energy ②		120	mJ
$I_{\text{AR}}$	Avalanche Current ①		20	A

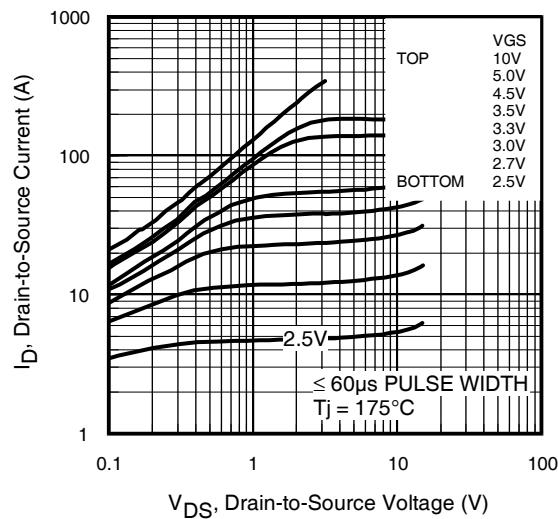
**Diode Characteristics**

	Parameter	Min.	Typ.	Max.	Units	Conditions
$I_s$	Continuous Source Current (Body Diode)			86 ④	A	MOSFET symbol showing the integral reverse p-n junction diode.
	Pulsed Source Current (Body Diode) ①			340		
$V_{\text{SD}}$	Diode Forward Voltage			1.0	V	$T_J = 25^\circ\text{C}, I_S = 20\text{A}, V_{\text{GS}} = 0\text{V}$ ③
$t_{\text{rr}}$	Reverse Recovery Time		24	36	ns	$T_J = 25^\circ\text{C}, I_F = 20\text{A}, V_{\text{DD}} = 15\text{V}$ $di/dt = 300\text{A}/\mu\text{s}$ ③
$Q_{\text{rr}}$	Reverse Recovery Charge		52	78	nC	

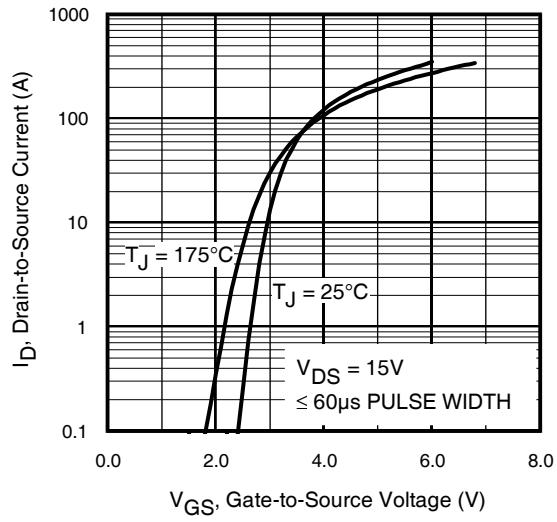




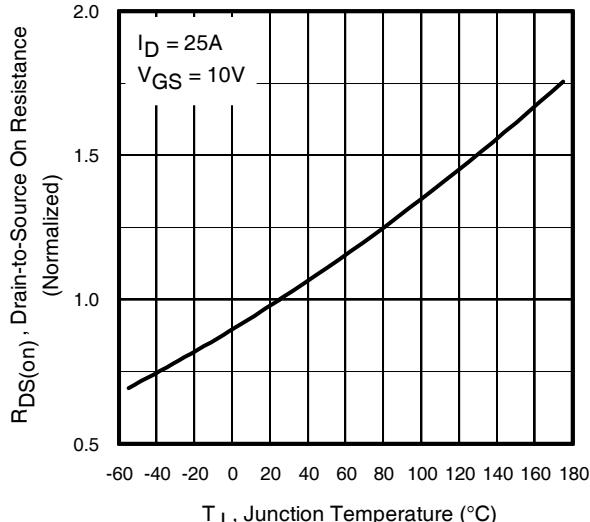
**Fig 1.** Typical Output Characteristics



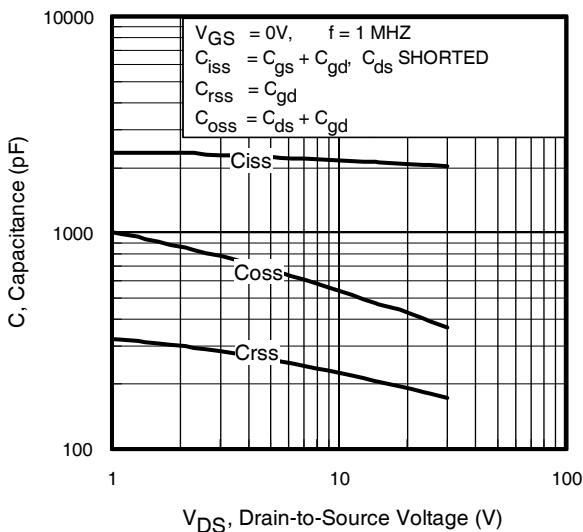
**Fig 2.** Typical Output Characteristics



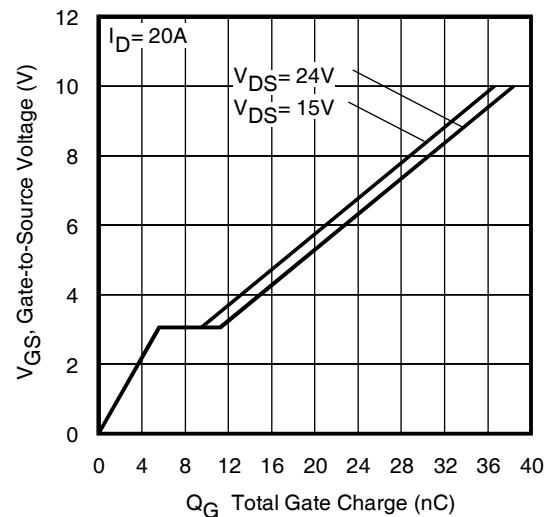
**Fig 3.** Typical Transfer Characteristics



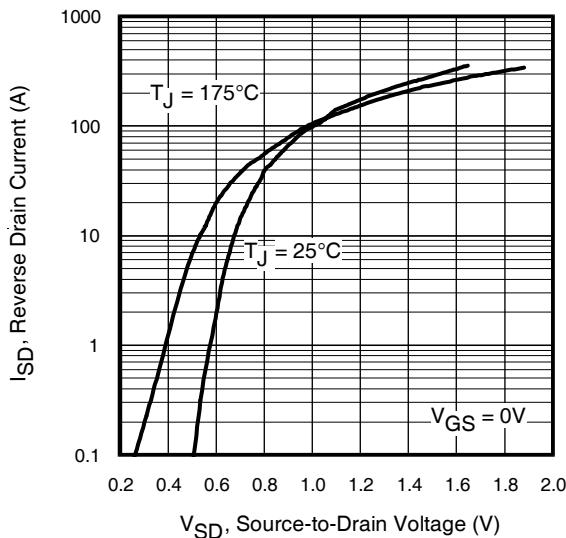
**Fig 4.** Normalized On-Resistance  
vs. Temperature



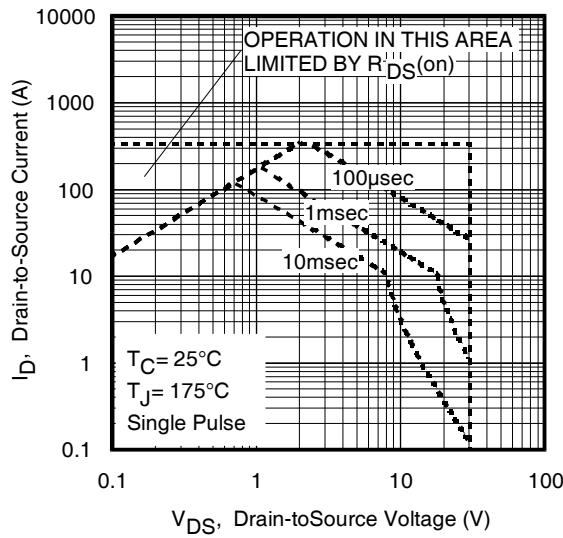
**Fig 5.** Typical Capacitance vs.  
Drain-to-Source Voltage



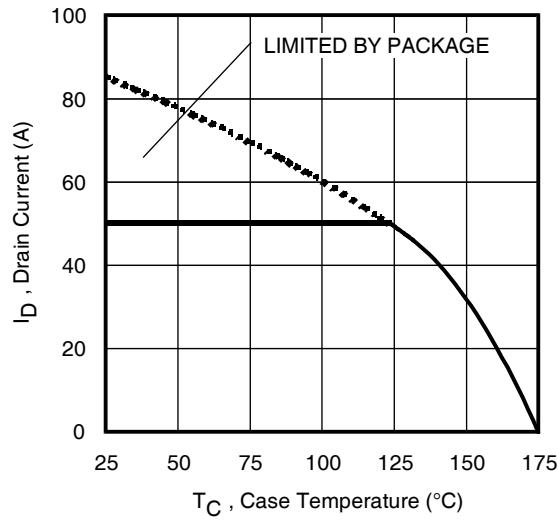
**Fig 6.** Typical Gate Charge vs.  
Gate-to-Source Voltage



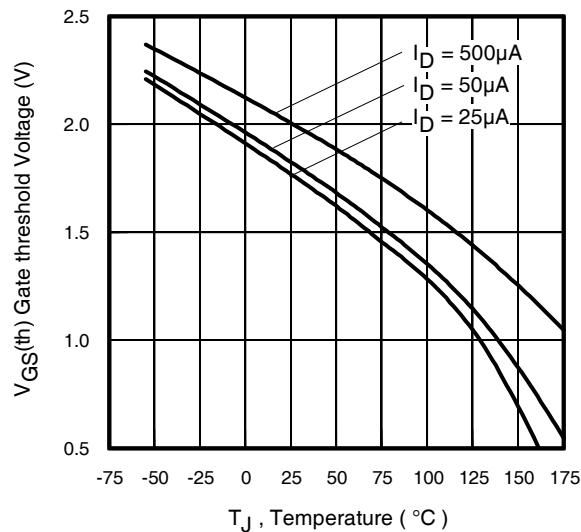
**Fig 7.** Typical Source-Drain Diode  
Forward Voltage



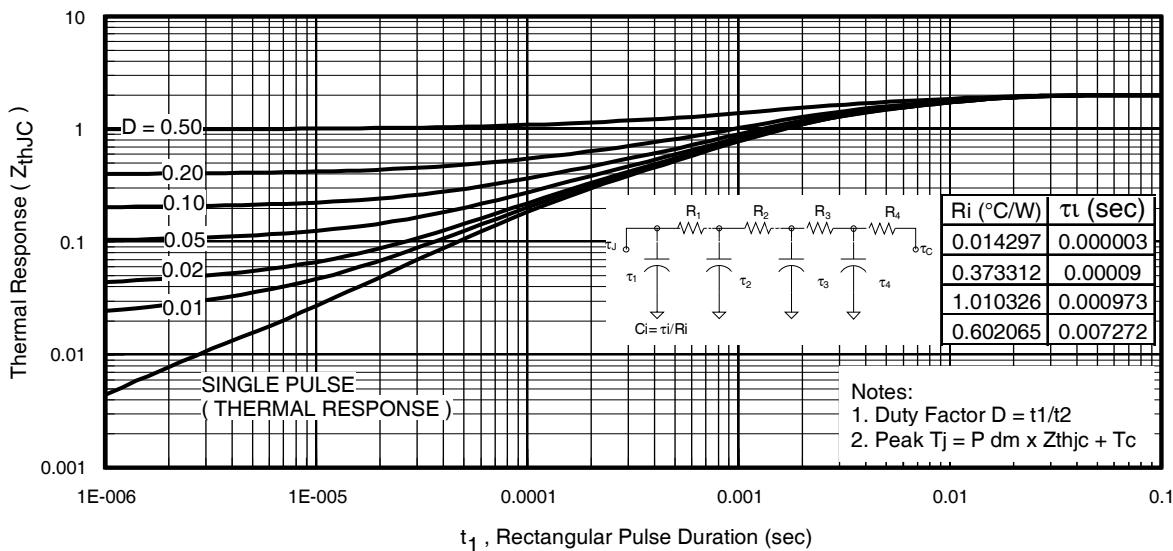
**Fig 8.** Maximum Safe Operating Area



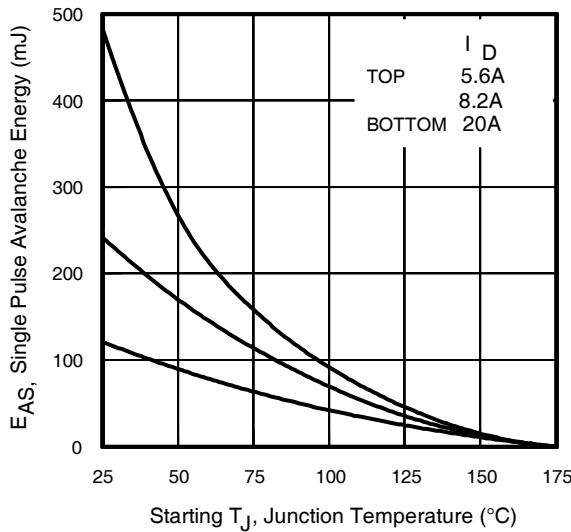
**Fig 9.** Maximum Drain Current vs.  
Case Temperature



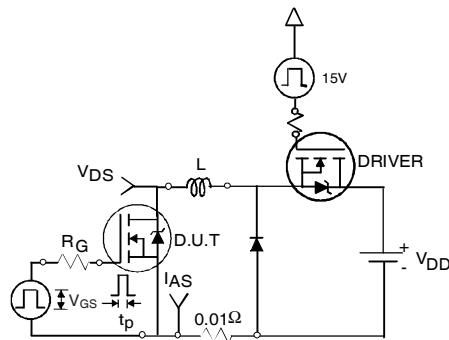
**Fig 10.** Threshold Voltage vs. Temperature



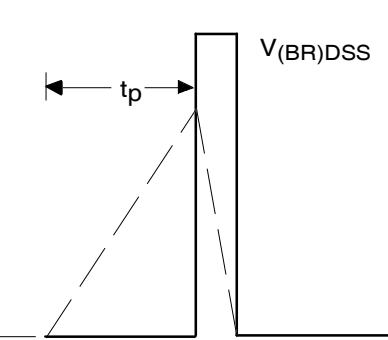
**Fig 11.** Maximum Effective Transient Thermal Impedance, Junction-to-Case



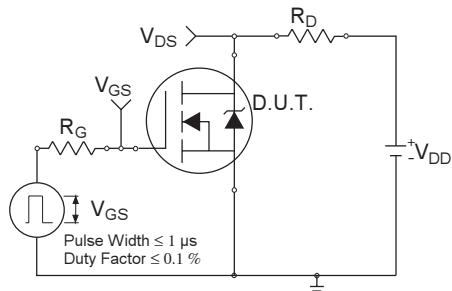
**Fig 12a.** Maximum Avalanche Energy Vs. Drain Current



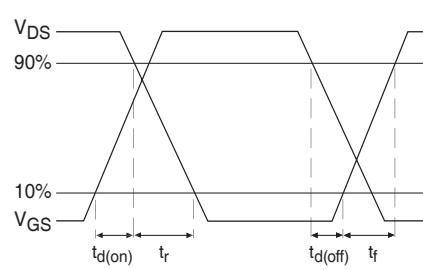
**Fig 12b.** Unclamped Inductive Test Circuit



**Fig 12c.** Unclamped Inductive Waveforms

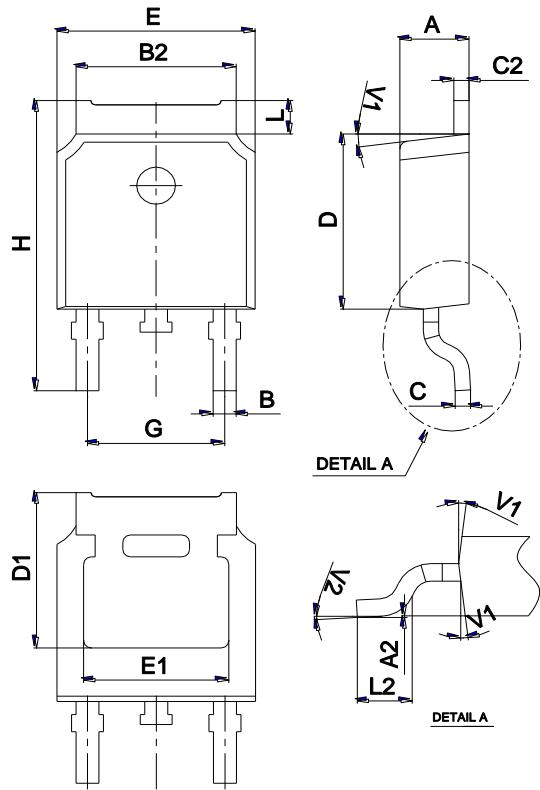


**Fig 13a.** Switching Time Test Circuit



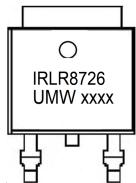
**Fig 13b.** Switching Time Waveforms

## Package Mechanical Data TO-252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

## Marking



## Ordering information

Order code	Package	Baseqty	Deliverymode
UMW IRLR8726TR	TO-252	2500	Tape and reel